NSN 5961-01-324-2425

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View Online at https://aerobasegroup.com/nsn/5961-01-324-2425 **Inclosure Material:** Plastic **Overall Length:** 16.51 millimeters **Terminal Length:** 14.73 millimeters **Overall Height:** 4.82 millimeters **Overall Width:** 10.66 millimeters **Function For Which Designed:** Switching **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Mounting Method:** Terminal and unthreaded hole Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 200.0 collector to emitter voltage, dc with base short-circuited to emitter and 125.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 4.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 31.25 watts small-signal input power, common-collector absolute **Transfer Ratio:** 30.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life:

Demilitarization: No

Unit Of Measure:

N/a

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